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Substitute for form 1449APTO	Complete if Known			
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)	Application Number	10/765,301		
	Filing Date	January 27, 2004		
	First Named Inventor	Leslie, Terrence		
	<b>Group Art Unit</b>	2815		
	Examiner Name	Landau, Matthew		
Sheet 1 of 1	Attorney Docket No: 3	303.860US1		

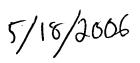
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INFORMATION DISCLOSURE	Complete if Known				
STATEMENT BY APPLICANT (Use as many sheets as necessary)	Application Number	10/765,301			
	Filing Date	January 27, 2004			
	First Named Inventor	Leslie, Terrence			
	Group Art Unit	2815			
	Examiner Name	Landau, Matthew			
Sheet 1 of 1	Attorney Docket No: 3	303.860US1			

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Examiner Name

Attorney Docket No: 303.860US1

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	[	publisher, city and/or country where published.	

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Martin C. Larlan

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